

T-29-11

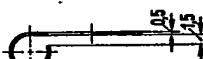
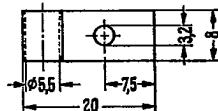
## for AF input and driver stages of medium performance

AC 151 and AC 151 r are alloyed germanium PNP transistors in 1A 3 DIN 41871 case (similar to TO-1).

The leads of these transistors are electrically insulated from the case. The collector terminal is marked by a red dot at the rim of the case. A fixing part (heat sink<sup>1)</sup>) is provided for fixing on the chassis; it has to be ordered separately.

Not for new design

Type	Ordering code
AC 151 IV	Q60103-X151-D
AC 151 rIV	Q60103-X151-D1
AC 151 V	Q60103-X151-E
AC 151 rV	Q60103-X151-E1
AC 151 VI	Q60103-X151-F
AC 151 rVI	Q60103-X151-F1
AC 151 VII	Q60103-X151-G
Heat sink	Q62901-B1



Approx. weight 1 g

Dimensions in mm

Approx. weight 2 g

## Maximum ratings

	AC 151 AC 151 r	
Collector-emitter voltage	24	V
Collector-emitter voltage ( $V_{BE} \geq 0.2$ V)	32	V
Collector-base voltage	32	V
Emitter-base voltage	10	V
Collector current	200	mA
Base current	40	mA
Junction temperature	90	°C
Storage temperature range	-55 to +75	°C
Total power dissipation	900	mW

## Thermal resistance

Junction to ambient air	$R_{thJA}$	$\leq 300$	K/W
Junction to case	$R_{thJC}$	$\leq 50$	K/W

1) Thermal resistance between transistor case and heat sink below the fixing screw at careful mounting:  $R_{th} \leq 10$  K/W

**Static characteristics ( $T_{amb} = 25^\circ C$ )<sup>3)</sup>**

	<b>AC 151</b>	<b>AC 151 r</b>	
Collector-emitter saturation voltage ( $-I_C = 200 \text{ mA}; h_{FE} = 20$ )	$-V_{CEsat}^{1)}$	0.13 (<0.22)	V
Collector-emitter saturation voltage	$-V_{CEsat}$	0.25 (<0.4) <sup>2)</sup>	V
Collector cutoff current ( $V_{CBO} = 10 \text{ V}$ )	$-I_{CBO}$	<10	$\mu\text{A}$
Collector cutoff current ( $V_{CBO} = 32 \text{ V}$ )	$-I_{CBO}$	6 (<25)	$\mu\text{A}$
Collector cutoff current ( $-V_{CEV} = 32 \text{ V}$ ; $(V_{BE} \geq 0.2 \text{ V})$ )	$-I_{CEV}$	6 (<25)	$\mu\text{A}$
Emitter cutoff current ( $-V_{EBO} = 10 \text{ V}$ )	$-I_{EBO}$	4 (<25)	$\mu\text{A}$

**Dynamic characteristics ( $T_{amb} = 25^\circ C$ )**

	<b>AC 151</b>	<b>AC 151r</b>	
Cutoff frequency ( $-I_C = 1 \text{ mA}; -V_{CE} = 5 \text{ V}$ )	$f_{hfe}$	15	kHz
Transition frequency	$f_T$	1.5	MHz
Base intrinsic resistance	$r_{bb'}$	75	$\Omega$
Collector-junction capacitance	$C_{b'e}$	27	pF
Noise figure ( $-I_C = 0.5 \text{ mA}; -V_{CE} = 5 \text{ V};$ $f = 200 \text{ Hz}; R_g = 500 \Omega; f = 1 \text{ kHz}$ )	NF	4 (<10)	dB

The transistors AC 151 and AC 151r are grouped according to the small signal current gain  $h_{fe}$  and marked by Roman numerals.

Operating point: ( $-I_C = 2 \text{ mA}; -V_{CE} = 1 \text{ V}; f = 1 \text{ kHz}$ )

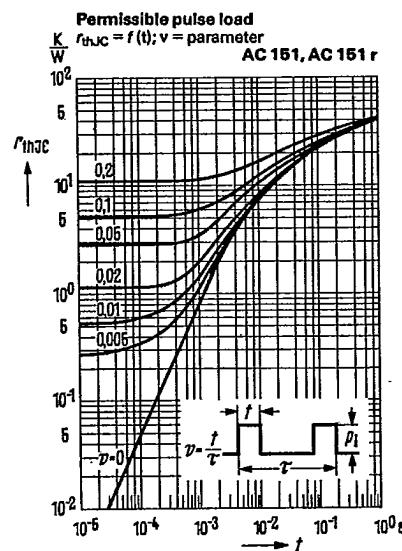
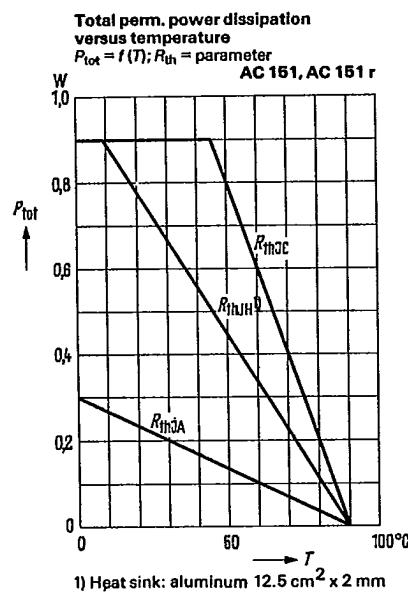
$h_{fe}$ group	<b>IV</b>	<b>V</b>	<b>VI</b>	<b>VII</b>	
<b>Type</b>	<b>AC 151 r</b>	<b>AC 151 r</b>	<b>AC 151 r</b>	—	
	<b>AC 151</b>	<b>AC 151</b>	<b>AC 151</b>	<b>AC 151</b>	
$h_{11e}$	0.75 (0.4 to 1.3)	1.2 (0.6 to 2.1)	1.8 (1.0 to 3.2)	2.7 (1.7 to 5.3)	k $\Omega$
$h_{12e}$	9 (<20)	13 (<25)	16 (<28)	19 (<30)	$10^{-4}$
$h_{21e}$	45 (30 to 60)	75 (50 to 100)	110 (75 to 150)	170 (125 to 250)	—
$h_{22e}$	100 (<200)	140 (<250)	160 (<280)	160 (<300)	$\mu\text{s}$

1) The transistor is overloaded to such a degree that the DC current gain decreases to  $h_{FE} = 20$ .

2) ( $-I_C = 200 \text{ mA}$  for the characteristic which, at a constant base current, intersects the operating point, where  
 $-I_C = 200 \text{ mA}; -V_{CE} = 0.5 \text{ V}$ )

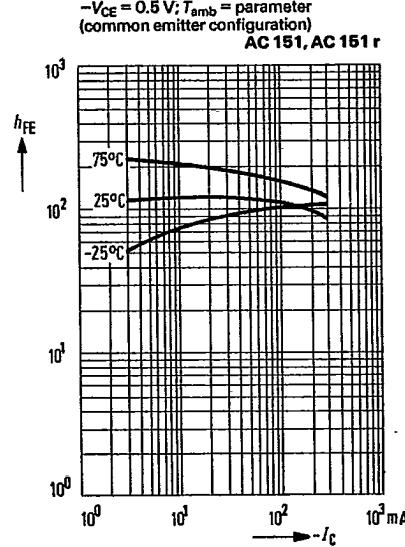
3) See also next page

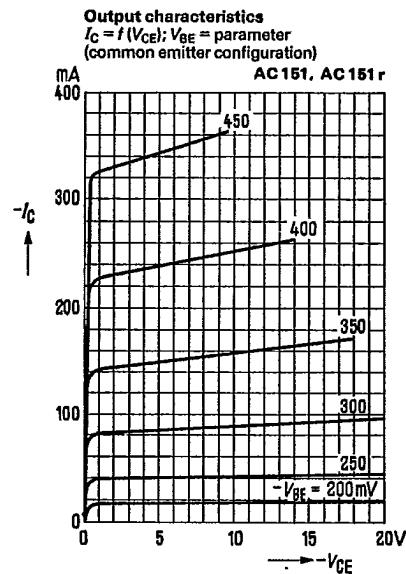
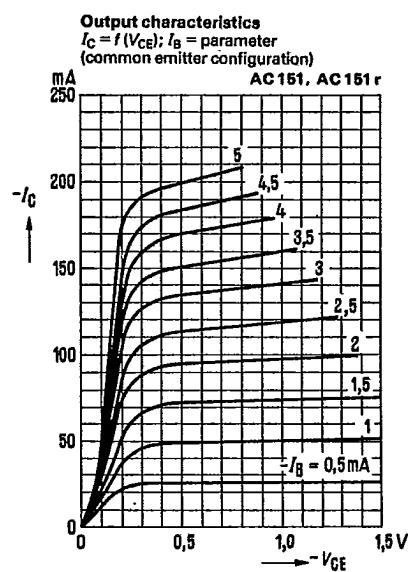
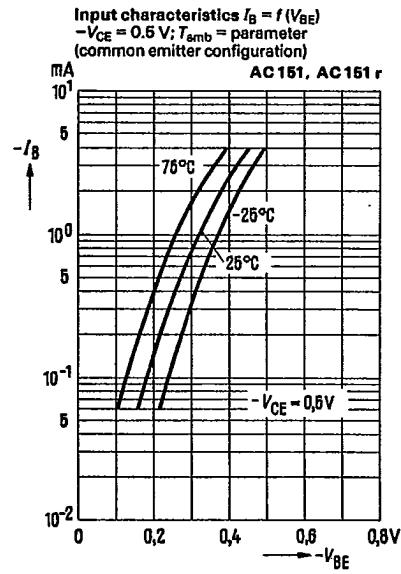
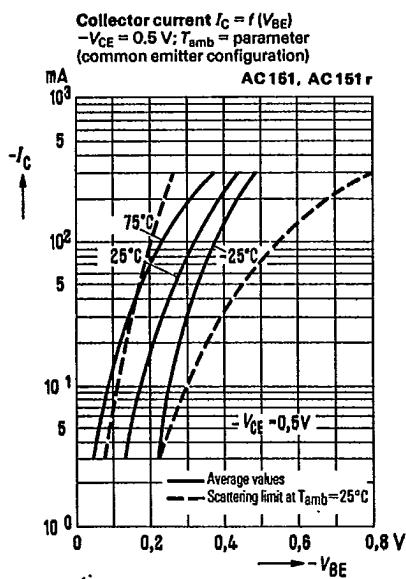
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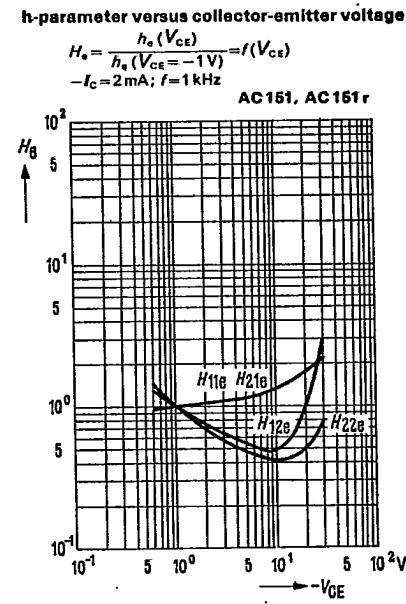
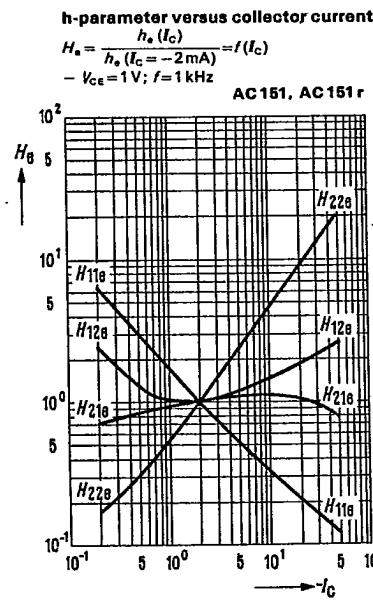
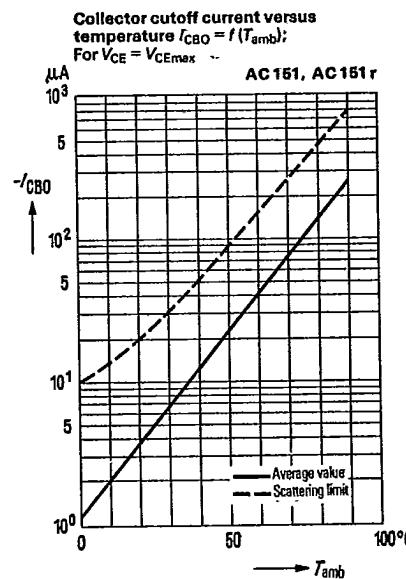
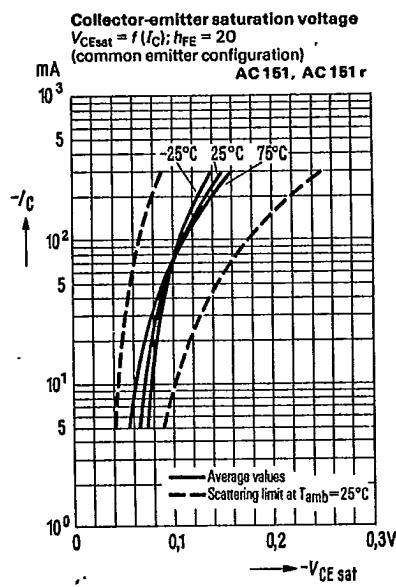
**Static characteristics ( $T_{\text{amb}} = 25^\circ\text{C}$ )**  
 $-V_{\text{CE}} = 0.5 \text{ V}$

Type	<b>AC 151, 151 r</b>		
$-I_C$ mA	$-I_B$ mA	$h_{\text{FE}}$ $I_C/I_B$	$-V_{\text{BE}}$ V
2	0.043	47	0.125 (<0.2)
10	0.2	50	0.18 (<0.3)
50	-	-	-
100	2,222	45	0.32 (<0.55)
200	5	40	0.39 (<0.7)

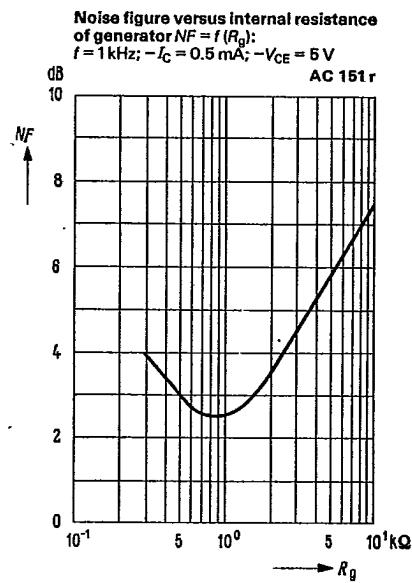
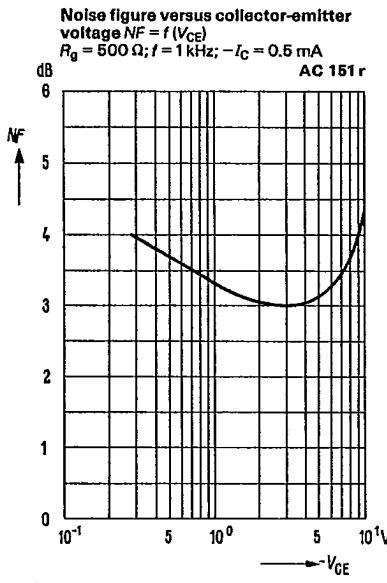
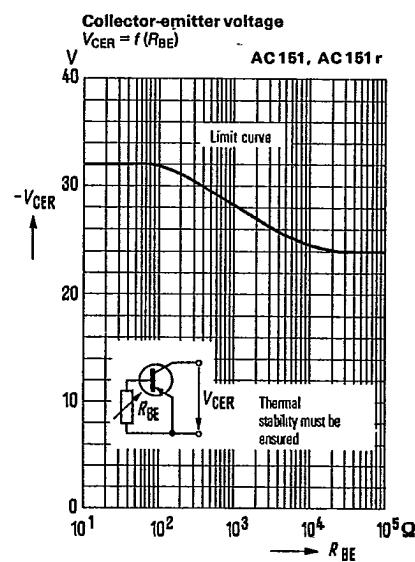
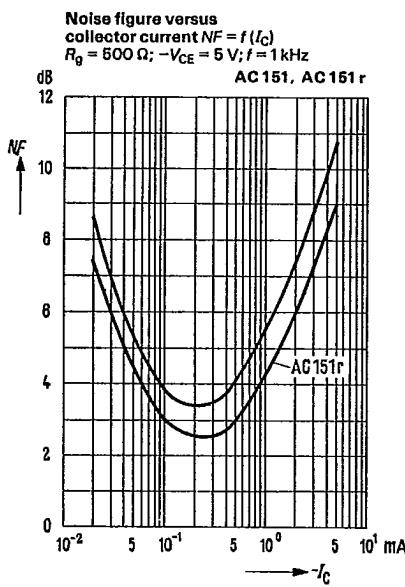


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AC 151  
AC 151 r

1516

C-13